

MBRS320T3, MBRS330T3, MBRS340T3, MBRS360T3

...employing the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes, in surface mount applications where compact size and weight are critical to the system.

- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- Very Low Forward Voltage Drop
(0.5 Volts Max @ 3.0 A, $T_J = 25^\circ\text{C}$)
- Excellent Ability to Withstand Reverse Avalanche Energy Transients
- Guardring for Stress Protection

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 217 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes:
260°C Max. for 10 Seconds
- Shipped in 16 mm Tape and Reel, 2500 units per reel
- Polarity: Notch in Plastic Body Indicates Cathode Lead
- Marking: B32, B33, B34, B36

MAXIMUM RATINGS

Please See the Table on the Following Page

Preferred Devices

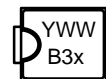
Surface Mount Schottky Power Rectifier

**SCHOTTKY BARRIER
RECTIFIERS
3.0 AMPERES
20, 30, 40, 60 VOLTS**



SMC
CASE 403
PLASTIC

MARKING DIAGRAM



B3x = Device Code
x = 2, 3, 4 or 6
Y = Year
W = Work Week

ORDERING INFORMATION

Device	Package	Shipping
MBRS320T3	SMC	2500/Tape & Reel
MBRS330T3	SMC	2500/Tape & Reel
MBRS340T3	SMC	2500/Tape & Reel
MBRS360T3	SMC	2500/Tape & Reel

Preferred devices are recommended choices for future use and best overall value.



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MAXIMUM RATINGS

Rating	Symbol	MBRS320T3	MBRS330T3	MBRS340T3	MBRS360T3	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	20	30	40	60	Volts
Average Rectified Forward Current	$I_{F(AV)}$	3.0 @ $T_L = 100^\circ\text{C}$ 4.0 @ $T_L = 90^\circ\text{C}$				Amps
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I_{FSM}	80	80	80	80	Amps
Operating Junction Temperature	T_J	- 65 to +125	- 65 to +125	- 65 to +125		$^\circ\text{C}$

THERMAL CHARACTERISTICS

Thermal Resistance — Junction to Lead	$R_{\theta JL}$	11	11	11	11	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS

Maximum Instantaneous Forward Voltage (Note 1.) ($i_F = 3.0\text{ A}$, $T_J = 25^\circ\text{C}$)	V_F	0.50	0.50	0.525	0.740	Volts
Maximum Instantaneous Reverse Current (Note 1.) (Rated dc Voltage, $T_J = 25^\circ\text{C}$) (Rated dc Voltage, $T_J = 100^\circ\text{C}$)	i_R	2.0 20	2.0 20	2.0 20	0.5 20	mA

1. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$.